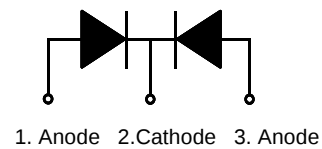
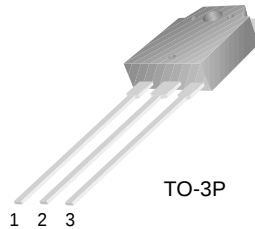


FFA60UP20DN

Features

- Ultrafast with soft recovery
(@ $I_F = 1A$), < 40ns
- Reverse Voltage, 200V
- Forward Voltage (@ $T_C = 100^\circ C$), < 1V



Applications

- Power switching circuits
- Output rectifiers
- Freewheeling diodes
- Switching mode power supply

Absolute Maximum Ratings (per diode) $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Peak Repetitive Reverse Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current @ $T_C = 100^\circ C$	30	A
I_{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	300	A
T_J, T_{STG}	Operating Junction and Storage Temperature	- 65 to +150	$^\circ C$

Thermal Characteristics

Symbol	Parameter	Value	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	1.4	$^\circ C/W$

Electrical Characteristics (per diode) $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Min.	Typ.	Max.	Units
V_{FM}^*	Maximum Instantaneous Forward Voltage				V
	$I_F = 30A$ $T_C = 25^\circ C$	-	-	1.15	
I_{RM}^*	Maximum Instantaneous Reverse Current @ rated V_R				μA
	$T_C = 25^\circ C$ $T_C = 100^\circ C$	-	-	10 100	
t_{rr}	Reverse Recovery Time	-	32	-	ns
I_{rr}	Reverse Recovery Current	-	2.4	-	A
Q_{rr}	Reverse Recovery Charge ($I_F = 30A$, $di/dt = 200A/\mu s$)	-	38.4	-	nC
t_{rr}	Maximum Reverse Recovery Time ($I_F = 1A$, $di/dt = 100A/\mu s$)	-	-	40	ns
W_{AVL}	Avalanche Energy (L=40mH)	2	-	-	mJ

* Pulse Test: Pulse Width=300 μs , Duty Cycle=2%

Typical Characteristics

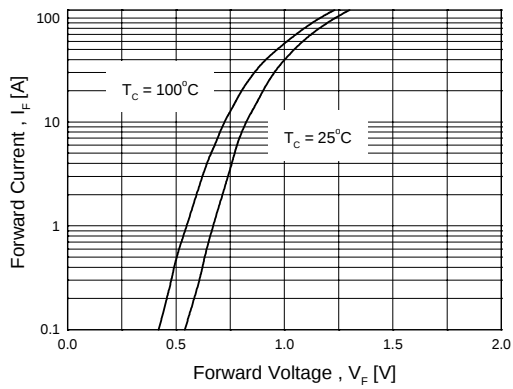


Figure 1. Typical Forward Voltage Drop vs. Forward Current

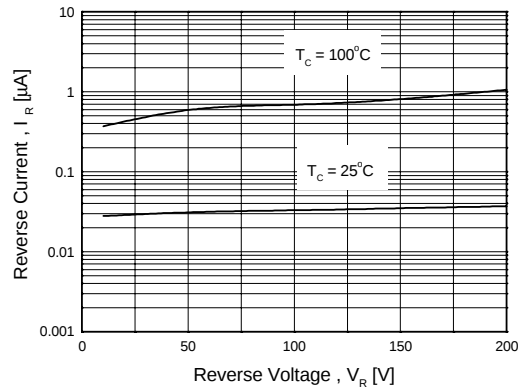


Figure 2. Typical Reverse Current vs. Reverse Voltage

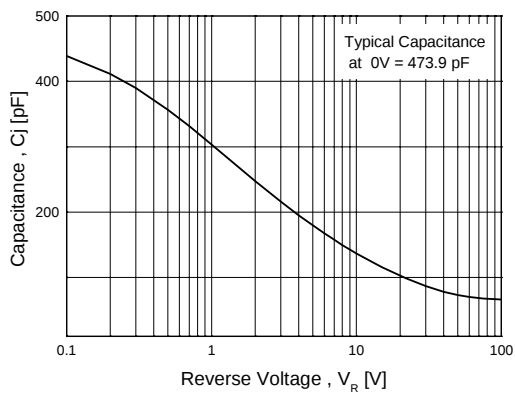


Figure 3. Typical Junction Capacitance

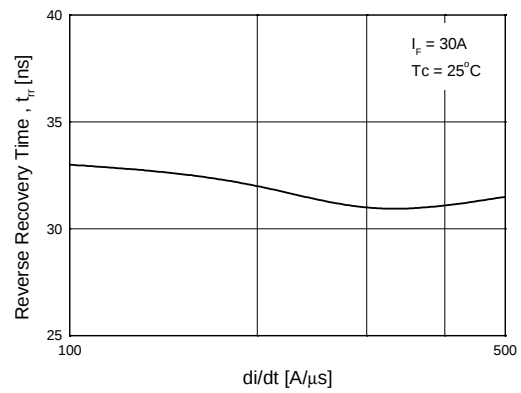


Figure 4. Typical Reverse Recovery Time vs. di/dt

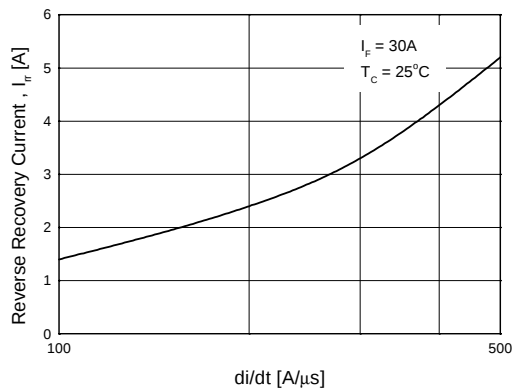


Figure 5. Typical Reverse Recovery Current vs. di/dt

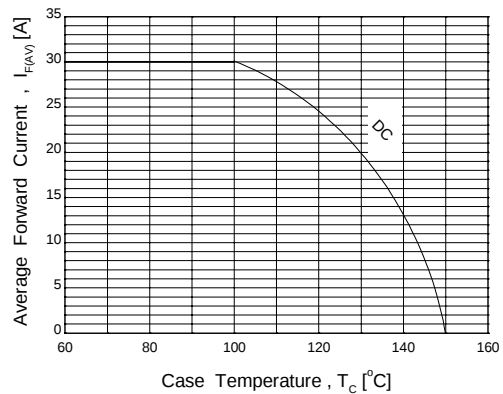


Figure 6. Forward Current Derating Curve